



Product Summary

BV _{DSS}	Rds(on)	Ι _D T _A = +25°C
	$240m\Omega @ V_{GS} = 4.5V$	1.7A
20V	300mΩ @ V _{GS} = 2.5V	1.56A

Description and Applications

This new generation MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Power Management Functions
- Battery Operated Systems and Solid-State Relays
- Load Switch

Features and Benefits

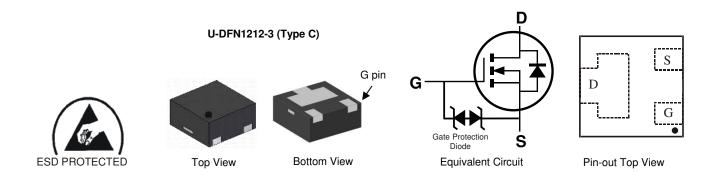
- Low On-Resistance
- Very Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)

N-CHANNEL ENHANCEMENT MODE MOSFET

- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Case: U-DFN1212-3
- Case Material: Molded Plastic; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe; Solderable per MIL-STD-202, Method 208 ^(e)
- Terminal Connections: See Diagram
- Weight: 0.005 grams (Approximate)



Ordering Information (Note 4)

Part Number	Case	Packaging
DMN2310UFD-7	U-DFN1212-3 (Type C)	3,000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information

U-DFN1212-3 (Type C)



BE5 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: I = 2021) M = Month (ex: 9 = September)

Year	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	Н		J	K	L	М	Ν	0	Р	R	S	Т
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Site 2

U-DFN1212-3 (Type C)



BE5 = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 1 = 2021) W = Week (ex: a = Week 27; z Represents Week 52 and 53) X = Internal Code (ex: U = Monday)

Date Code Key

Year	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	0	1	2	3	4	5	6	7	8	9	0	1
Week		1.	-26			27	'-52			Ę	53	
Code	A-Z				a-z				Z			
nternal Code	Su	ın	Mor	n	Tue		Wed	Thu		Fri		Sat
Code		-	11		V		W	X		Y		7



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	VDSS	20 V			
Gate-Source Voltage	V _{GSS}	±8	V		
Continuous Drain Current (Note 6) $V_{GS} = 4.5V$	ID	1.7 1.4	A		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	ldм	4.7	A		
Maximum Body Diode Forward Current (Note 6)			ls	1.2	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	0.67	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	RθJA	187	°C/W
Total Power Dissipation (Note 6)		PD	1.1	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R _{θJA}	114	°C/W
Thermal Resistance, Junction to Case (Note 6)		Rejc	120	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						÷
Drain-Source Breakdown Voltage	BVDSS	20	—	—	V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}		—	1.0	μΑ	$V_{DS} = 20V, V_{GS} = 0V$
Gate-Source Leakage	lgss		—	±10	μΑ	$V_{GS} = \pm 8V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	VGS(TH)	0.45	—	0.95	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$
		_	150	240		VGS = 4.5V, ID = 1A
Static Drain-Source On-Resistance	Descent		190	300		$V_{GS} = 2.5V, I_D = 750mA$
Static Drain-Source On-Resistance	Rds(on)	_	250	400	mΩ	V _{GS} = 1.8V, I _D = 500mA
		_	320	500		$V_{GS} = 1.5V, I_D = 250mA$
Diode Forward Voltage	V _{SD}	_	0.7	1.2	V	$V_{GS} = 0V, I_{S} = 500mA$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss		38	_	pF	
Output Capacitance	Coss	_	10	—	pF	$V_{DS} = 10V, V_{GS} = 0V,$
Reverse Transfer Capacitance	Crss	—	6	_	pF	f = 1.0MHz
Total Gate Charge	Qg	_	0.7		nC	
Gate-Source Charge	Qgs	—	0.1	_	nC	$V_{GS} = 4.5V, V_{DS} = 10V,$
Gate-Drain Charge	Q _{gd}		0.1	—	nC	$I_D = 1A$
Turn-On Delay Time	tD(ON)		5.5		ns	
Turn-On Rise Time	tR	_	2.7		ns	$V_{DD} = 10V, V_{GS} = 5V,$
Turn-Off Delay Time	tD(OFF)		183		ns	$R_L = 1.7\Omega, R_G = 6\Omega$
Turn-Off Fall Time	tF		49	_	ns	

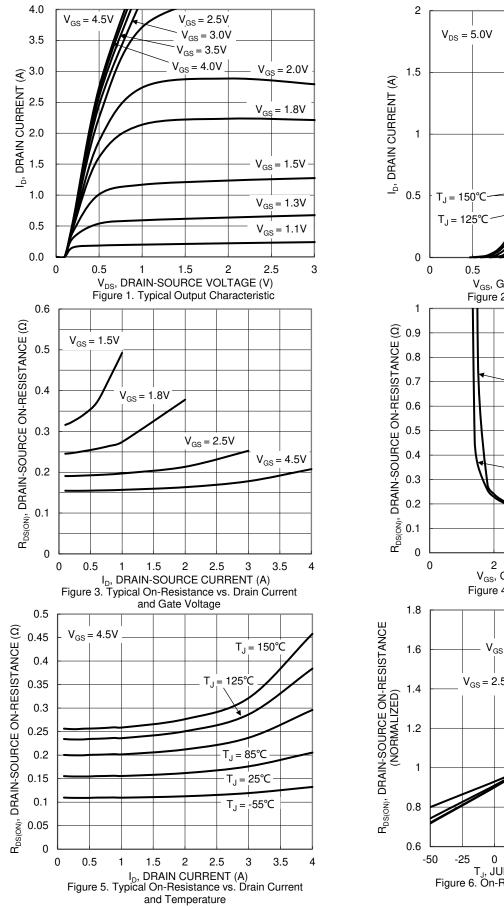
Notes:

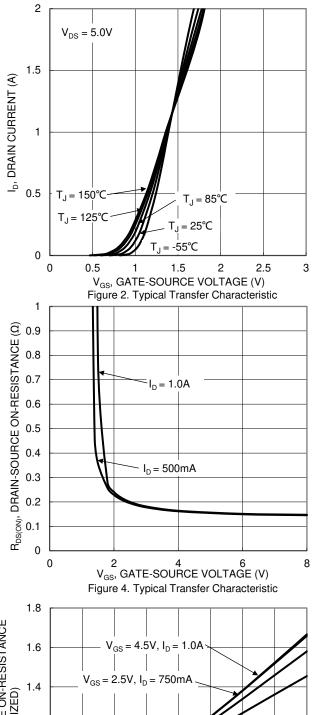
Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
Device mounted on FR-4 substrate PC board, 2oz copper, with thermal vias to bottom layer 1-inch square copper plate.

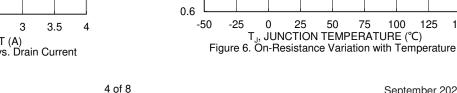
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to production testing.



DMN2310UFD







125

150

 $V_{GS} = 1.8V, I_{D} = 500mA$

100

V_{GS} = 1.5V, I_D = 200mA

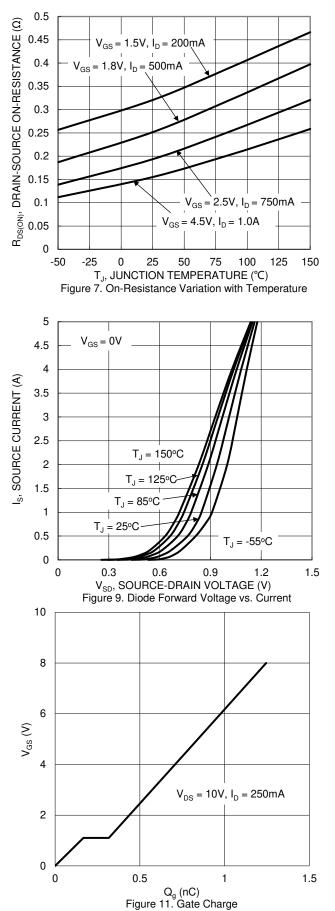
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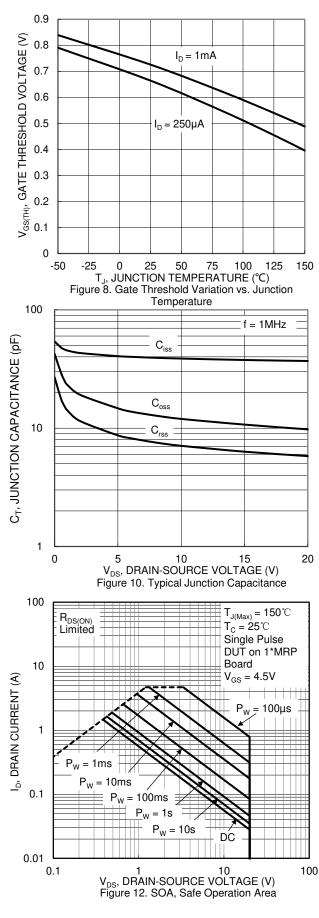
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DMN2310UFD Document number: DS42789 Rev. 3 - 2



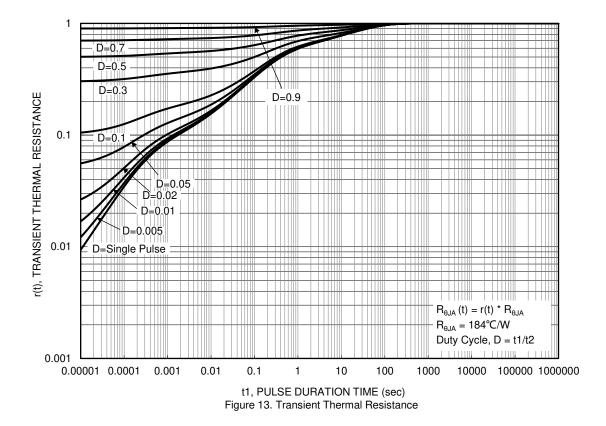
DMN2310UFD





DMN2310UFD Document number: DS42789 Rev. 3 - 2 September 2021 © Diodes Incorporated







Тур 0.50

0.02

0.13

0.32

0.22

1.20

0.85 0.80

1.20

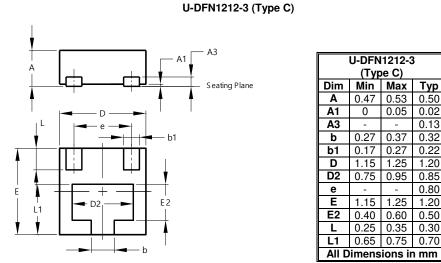
0.50

0.30

0.70

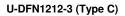
Package Outline Dimensions

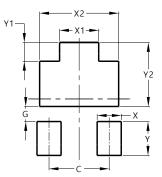
Please see http://www.diodes.com/package-outlines.html for the latest version.



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.





Dimensions	Value
Dimensions	(in mm)
С	0.800
G	0.200
Х	0.320
X1	0.520
X2	1.050
Y	0.450
Y1	0.250
Y2	0.850



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